

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L4	189	(silicon or si) near5 substrate near5 purity same semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 14:29
L3	0	(silicon or si) near5 substrate near5 purity near5 "99.99"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 14:29
L2	7603	(silicon or si) near5 substrate near5 purity "99.99"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 14:29
L1	507	(silicon or si) near5 substrate near5 purity	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 14:29
S2	1181	(masaki near2 mizutani or shunichi near2 ishihara or katsumi near2 nakagawa or takehito near2 yoshino or shoji near2 nishida).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 14:30
L6	49	(masaki near2 mizutani or shunichi near2 ishihara or katsumi near2 nakagawa or takehito near2 yoshino or shoji near2 nishida).in. and (silicon or si) near10 purity and solar near2 cell	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 14:35
L5	53	(masaki near2 mizutani or shunichi near2 ishihara or katsumi near2 nakagawa or takehito near2 yoshino or shoji near2 nishida).in. and (silicon or si) near10 purity	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 14:35
L7	18	(masaki near2 mizutani or shunichi near2 ishihara or katsumi near2 nakagawa or takehito near2 yoshino or shoji near2 nishida).in. and (silicon or si) near10 purity same solar near2 cell	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 14:44
L8	1	(masaki near2 mizutani or shunichi near2 ishihara or katsumi near2 nakagawa or takehito near2 yoshino or shoji near2 nishida).in. and (silicon or si) near10 purity same solar near2 cell and silicon near10 inclin\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 14:45

EAST Search History

L10	806	(silicon or si) near5 (layer or film) near10 inclin\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 14:48
L11	45	(silicon or si) near5 (layer or film) near10 inclin\$5 and solar	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 15:55
L12	4893	(si or silicon) near10 "p+"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 15:56
L15	0	(si or silicon) near10 "p+" near10 wafer near10 "%"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 15:57
L14	901626	(si or silicon) near10 "p+" near10 wafer ner10 "%"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 15:57
L13	13	(si or silicon) near10 "p+" near10 wafer same solar	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 15:57
L19	131	(si or silicon) near10 wafer near10 purity and p\$1type	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 16:00
L18	791	(si or silicon) near10 wafer near10 purity	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 16:00
L17	0	(si or silicon) near10 "p+" near10 wafer near10 purity	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 16:00
L16	17	(si or silicon) near10 "p+" near10 wafer near10 concentrat\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 16:00

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L22	406	(si or silicon) near10 wafer near10 "%"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 16:02
L21	8368	(si or silicon) near10 wafer near10 "5"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 16:02
L20	5	(si or silicon) near10 wafer near10 purity near15 p\$1type	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 16:02
L23	2	(si or silicon) near10 wafer near10 "% same solar	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 16:03
L24	19	(si or silicon) near10 wafer near10 "% and solar	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 16:04
L25	87	(si or silicon) near10 p\$1type near10 "%"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 17:08
L27	16	(si or silicon) near10 p\$1type near10 "% near5 (substrate or wafer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 17:09
L26	37	(si or silicon) near10 p\$1type near10 "% and solar	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 17:09
L30	1	"20020077035" and perborate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 17:35
L29	2	"20020077035"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 17:35

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L32	1	31 and inclin\$5 near5 substrate and purity near5 (si or silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 18:00
L31	1195	(masaki near2 mizutani or shunichi near2 ishihara or katsumi near2 nakagawa or takehito near2 yoshino or shoji near2 nishida).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 18:00
L9	1	(masaki near2 mizutani or shunichi near2 ishihara or katsumi near2 nakagawa or takehito near2 yoshino or shoji near2 nishida).in. and (silicon or si) near10 purity same solar near2 cell and (si or substrate or silicon) near10 inclin\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 18:00
L34	2	"5575862".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 18:03
L33	52	31 and purity near5 (si or silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 18:03